# **High Voltage Transistor Surface Mount**

# **NPN Silicon**

#### **Features**

- PZTA42T1G is Complement to PZTA92T1G
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

# **MAXIMUM RATINGS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage (Open Base)	V <sub>CEO</sub>	300	Vdc	
Collector–Base Voltage (Open Emitter)	V <sub>CBO</sub>	300	Vdc	
Emitter–Base Voltage (Open Collector)	V <sub>EBO</sub>	6.0	Vdc	
Collector Current (DC)	I <sub>C</sub>	500	mAdc	
Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 1)	P <sub>D</sub>	1.5	W	
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C	
Junction Temperature	TJ	150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Device mounted on a FR-4 glass epoxy printed circuit board 1.575 in x 1.575 in x 0.0625 in; mounting pad for the collector lead = 0.93 sq in.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient (Note 2)	$R_{\theta JA}$	83.3	°C/W

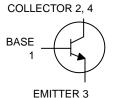
2. Device mounted on a FR-4 glass epoxy printed circuit board 1.575 in x 1.575 in x 0.0625 in; mounting pad for the collector lead = 0.93 sq in.



# ON Semiconductor®

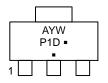
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# SOT-223 PACKAGE NPN SILICON HIGH VOLTAGE TRANSISTOR SURFACE MOUNT





#### **MARKING DIAGRAM**



P1D = Specific Device Code A = Assembly Location

Y = Year W = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
PZTA42T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
SPZTA42T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	<u>.</u>			
Collector-Emitter Breakdown Voltage (Note 3) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	300	_	Vdc
Collector-Base Breakdown Voltage $(I_C = 100 \mu Adc, I_E = 0)$	V <sub>(BR)</sub> CBO	300	_	Vdc
Emitter-Base Breakdown Voltage $(I_E = 100 \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	6.0	_	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 200 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	0.1	μAdc
Emitter-Base Cutoff Current $(V_{BE} = 6.0 \text{ Vdc}, I_C = 0)$	I <sub>EBO</sub>		0.1	μAdc
ON CHARACTERISTICS	•	•	•	•
DC Current Gain	h <sub>FE</sub>	25 40 40	- - -	-
DYNAMIC CHARACTERISTICS	<u>.</u>			
Current-Gain – Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	f <sub>T</sub>	50	_	MHz
Feedback Capacitance (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>re</sub>	-	3.0	pF
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 20 mAdc, I <sub>B</sub> = 2.0 mAdc)	V <sub>CE(sat)</sub>	-	0.5	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 20 mAdc, I <sub>B</sub> = 2.0 mAdc)	V <sub>BE(sat)</sub>	_	0.9	Vdc

<sup>3.</sup> Pulse Test Conditions,  $t_p$  = 300  $\mu s,\,\delta$  0.02.

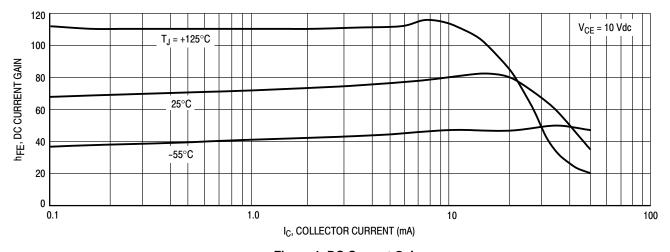


Figure 1. DC Current Gain

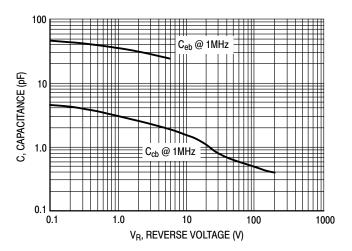
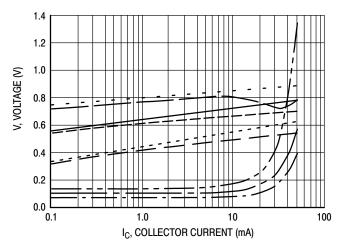


Figure 2. Capacitance



 VCE(sat)
 @ 25°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VCE(sat)
 @ 125°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VCE(sat)
 @ -55°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VBE(sat)
 @ 25°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VBE(sat)
 @ 125°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VBE(sat)
 @ 25°C, I<sub>C</sub>/I<sub>B</sub> = 10

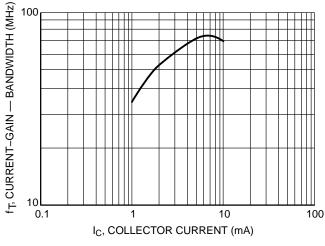
 VBE(sat)
 @ 25°C, I<sub>C</sub>/I<sub>B</sub> = 10

 VBE(on)
 @ 25°C, V<sub>CE</sub> = 10 V

 VBE(on)
 @ 125°C, V<sub>CE</sub> = 10 V

 VBE(on)
 @ -55°C, V<sub>CE</sub> = 10 V

Figure 3. "ON" Voltages



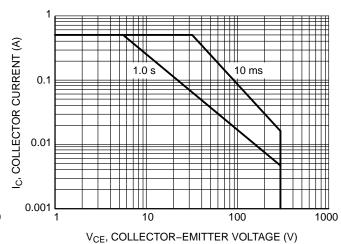
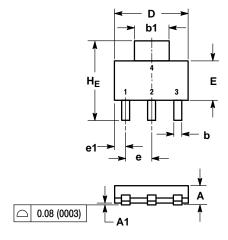


Figure 4. Current Gain Bandwidth Product

Figure 5. Safe Operating Area

#### PACKAGE DIMENSIONS

### **SOT-223 (TO-261)** CASE 318E-04 ISSUE N





- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
C	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
٦	0.20			800.0		
L	1.50	1.75	2.00	0.060	0.069	0.078
ΗE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	_	10°	0°	_	10°

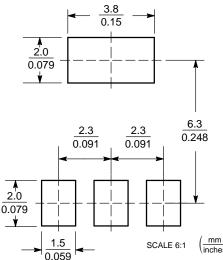
STYLE 1:

PIN 1. BASE 2. COLLECTOR

3. EMITTER
4. COLLECTOR

#### PINT\*





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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